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NFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

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Sheet 1 of

Complete if Known			
Application Number	10/731,269		
Filing Date December 8, 2003			
First Named Inventor Anand Murthy			
Art Unit . 2818			
Examiner Name David Nhu			
Attorney Docket Number	42P17811		

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No.'	Document Number Number - Kind Code* (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
74	1	US-6,214,679	04-10-2001	Murthy et al	
PH	2	US-2002/0130393	09-19-2002	Takayanagi et al	
P7-	3	US-6,440,851	08-27-2002	Agnello et al	
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	FOREIGN PATENT DOCUMENTS						
Examiner Cite Initials* No.*	Cite	Foreign Patent Document	Publication Date MM-DD-YYYY		Pages, Columns, Lines,	7.	
	No.	Country Code - Number - Kind Code (if known)		Name of Patentee or Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear		
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Examiner Signature	Luch	Date . Considered	6/	16/05

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'Applicant's unique citation designation number (optional):See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04:Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3).For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possibl@applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wtr) 08/11/2003.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

of 2 Sheet 2

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Attorney Docket Number	42P17811		

	NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²		
M	4	HARELAND S et al, "New Structural Approach for Reducing Punchthrough Current in Deep Submicrometre Mosfets and Extending Mosfet Scaling" X7 000404330 Electronics Letters IEE Stevanage, GB, vol. 29, no. 21, October 14, 1993, pp. 1894-1896	P		

Examiner	~ - 0	Date	
Signature	Dui Da	Considered	6/18/05

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